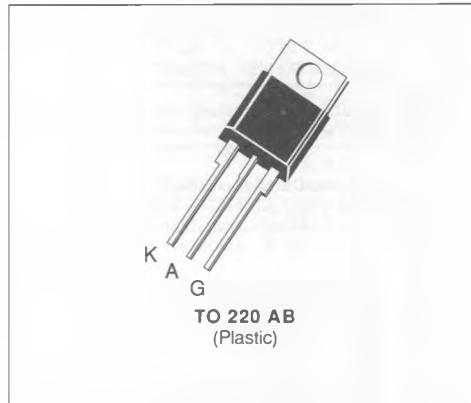


THYRISTORS

- GLASS PASSIVATED CHIP
- POSSIBILITY OF MOUNTING ON PRINTED CIRCUIT


DESCRIPTION

SCR's designed for motor control, heating controls, power supplies...

ABSOLUTE RATINGS (limiting values)

| Symbol | Parameter | TYN | | TYN | | Unit |
|--------------------|---|--------------------------|-------------|-------------|-------------|------------------------|
| | | 225 to 825 | 1025 - 1225 | 225 to 825 | 1025 - 1225 | |
| $I_{T(RMS)}$ | RMS on-state Current (1) | $T_c = 90^\circ\text{C}$ | | 25 | | A |
| $I_{T(AV)}$ | Mean on-state Current (1) | $T_c = 90^\circ\text{C}$ | | 16 | | A |
| I_{TSM} | Non Repetitive Surge Peak on-state Current (T_i initial = 25 °C) (2) | $t = 8.3 \text{ ms}$ | 315 | 260 | | A |
| | | $t = 10 \text{ ms}$ | 300 | 250 | | |
| I^2t | I^2t Value for Fusing | $t = 10 \text{ ms}$ | 450 | 310 | | A^2s |
| dI/dt | Critical Rate of Rise of on-state Current (3) | | | 100 | | $\text{A}/\mu\text{s}$ |
| T_{stg} T_i | Storage and Operating Junction Temperature Range | | | – 40 to 125 | | $^\circ\text{C}$ |
| | | | | – 40 to 125 | | $^\circ\text{C}$ |

| Symbol | Parameter | TYN | | | | | | Unit |
|------------------------|---------------------------------------|-----|-----|-----|-----|------|------|------|
| | | 225 | 425 | 625 | 825 | 1025 | 1225 | |
| V_{DRM} V_{RRM} | Repetitive Peak off-state Voltage (4) | 200 | 400 | 600 | 800 | 1000 | 1200 | V |

(1) Single phase circuit, 180° conduction angle.

(2) Half sine wave.

(3) $I_0 = 400 \text{ mA}$ $dI/dt = 1 \text{ A}/\mu\text{s}$.

(4) $T_i = 125^\circ\text{C}$.

THERMAL RESISTANCES

| Symbol | Parameter | Value | Unit |
|---------------|------------------------|-------|---------------------------|
| $R_{th(j-c)}$ | Junction-case for D.C. | 1.5 | $^\circ\text{C}/\text{W}$ |
| $R_{th(j-a)}$ | Junction-ambient | 60 | $^\circ\text{C}/\text{W}$ |

GATE CHARACTERISTICS (maximum values)

$$P_{GM} = 20 \text{ W } (t_p = 20 \mu\text{s})$$

$$I_{FGM} = 2 \text{ A } (t_p = 20 \text{ } \mu\text{s})$$

$$V_{RGM} = 5 \text{ V}$$

$$P_G(\text{AV}) = 0.5 \text{ W}$$

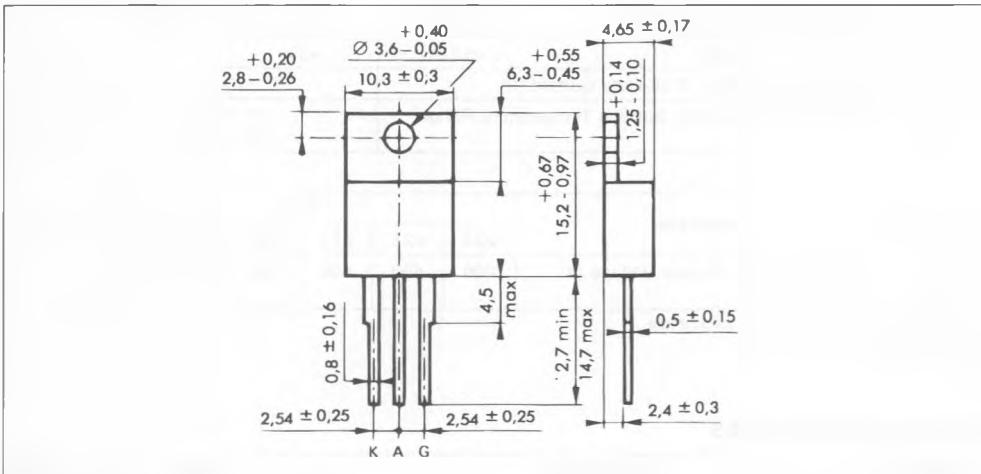
$$V_{FGM} = 15 \text{ V } (t_0 = 20 \mu\text{s})$$

ELECTRICAL CHARACTERISTICS

| Symbol | Test Conditions | | | Min. | Typ. | Max. | Unit |
|------------------|--|--|--|------|------|------|------|
| I _{GT} | T _j = 25 °C Pulse Duration > 20 µs | V _D = 12 V | R _L = 33 Ω | | | 40 | mA |
| V _{GT} | T _j = 25 °C Pulse Duration > 20 µs | V _D = 12 V | R _L = 33 Ω | | | 1.5 | V |
| V _{GD} | T _j = 125 °C | V _D = V _{DRM} | R _L = 3.3 kΩ | 0.2 | | | V |
| I _H | T _j = 25 °C | I _T = 100 mA | Gate Open | | | 50 | mA |
| I _L | T _j = 25 °C Pulse Duration > 20 µs | V _D = 12 V | I _G = 80 mA | | 80 | | mA |
| V _{TM} | T _j = 25 °C | I _{TM} = 50 A | t _p = 10 ms | | | 1.6 | V |
| I _{DRM} | T _j = 125 °C | V _{DRM} Specified | TYN 225 → 825 | 0.2 | 2.5 | mA | |
| | | | TYN 1025 - 1225 | 0.5 | 5 | | |
| I _{RRM} | T _j = 125 °C | V _{RRM} Specified | TYN 225 → 825 | 0.2 | 2.5 | mA | |
| | | | TYN 1025 - 1225 | 0.5 | 5 | | |
| t _{gt} | T _j = 25 °C I _G = 80 mA | V _D = V _{DRM} dI _G /dt = 0.85 A/µs | I _T = 50 A | | 2 | | µs |
| t _q | T _j = 125 °C V _D = 67 % V _{DRM} Gate Open | I _T = 50 A dI/dt = 30 A/µs | V _R = 25 V dv/dt = 50 V/µs | | 70 | | µs |
| dv/dt* | T _j = 125 °C Linear Slope up to V _D = 67 % V _{DRM} | Gate Open | TYN 225 → 825 | 500 | 750 | | V/µs |
| | | | TYN 1025 - 1225 | 250 | 500 | | |

* For higher guaranteed values, please consult us.

PACKAGE MECHANICAL DATA : TO 220 AB Plastic



Cooling method : by conduction (method C)

Marking : type number

Weight: 2 g

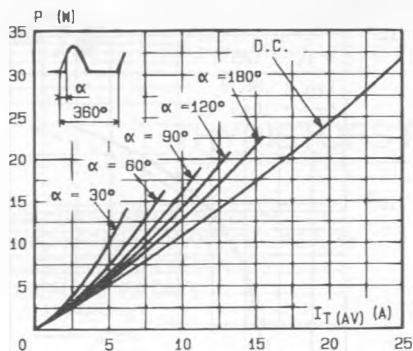


Fig.1 - Maximum mean power dissipation versus mean on-state current.

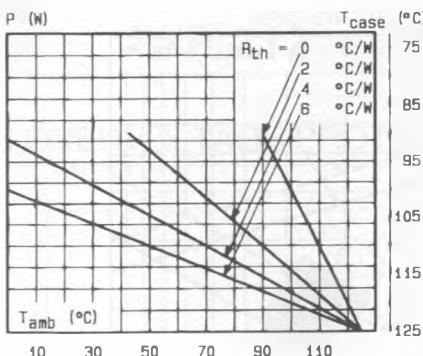


Fig.2 - Correlation between maximum mean power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink + contact.

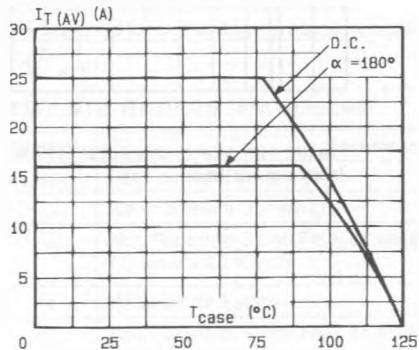


Fig.3 - Mean on-state current versus case temperature.

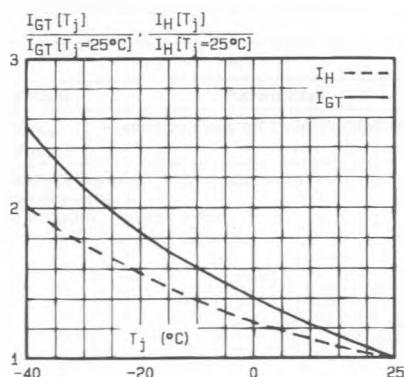


Fig.5 - Relative variation of gate trigger current and holding current versus junction temperature.

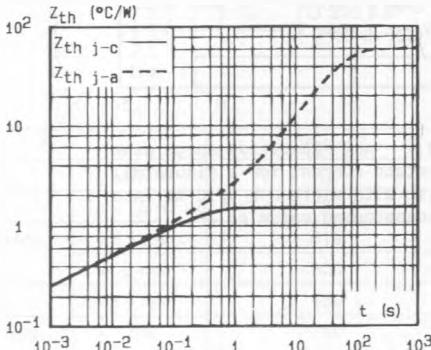


Fig.4 - Thermal transient impedance junction to case and junction to ambient versus pulse duration.

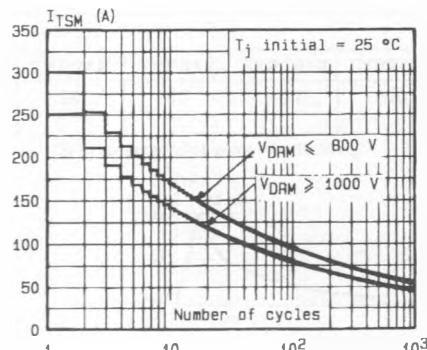


Fig.6 - Non repetitive surge peak on-state current versus number of cycles.

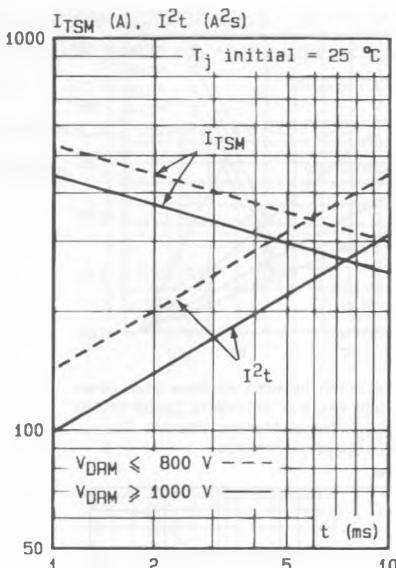


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width : $t \leq 10$ ms. and corresponding value of I^2t .

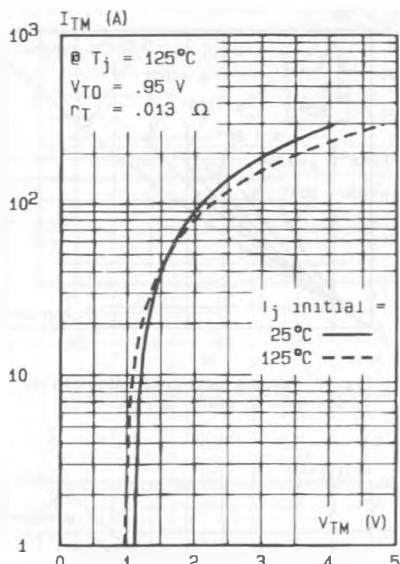


Fig.8 - On-state characteristics (maximum values).